

Single Output
Half-brick

# MILITARY COTS DC-DC CONVERTER

16-55V Continuous Input 16-60V Transient Input 10.2V Output 49A Output 95% @ 24.5A / 94% @ 49A

**Efficiency** 

Operation: -55°C to +100°C

The MilQor® series of Mil-COTS DC-DC converters brings SynQor's field proven high-efficiency synchronous rectification technology to the Military/Aerospace industry. SynQor's ruggedized encased packaging approach ensures survivability in demanding environments. Compatible with the industry standard format, these converters operate at a fixed frequency, and follow conservative component derating guidelines. They are designed and manufactured to comply with a wide range of military standards.

## **Safety Features**

- 2250 V, 30 M $\Omega$  input-to-output isolation
- Certified 62368-1 requirement for basic insulation (see Standards and Qualifications page)

#### **Mechanical Features**

- Industry standard half-brick pin-out
- Size: 2.49" x 2.39" x 0.51" (63.1 x 60.6 x 13.0 mm)
- Total weight: 5.2 oz. (146 g)
- Flanged baseplate version available

## **Operational Features**

- Modified extended input voltage range: 16-55V
- High efficiency, 94% at full rated load current
- Fixed frequency switching provides predictable EMI
- No minimum load requirement

## **Specification Compliance**

MCOTS series converters (with an MCOTS filter) are designed to meet:

- MIL-HDBK-704 (A-F)
- RTCA/DO-160E Section 16
- MIL-STD-1275 (B,D)
- DEF-STAN 61-5 (Part 6)/(5 or 6)
- MIL-STD-461 (C, D, E, F)

# **Mil**COTS



**Designed and Manufactured in the USA** 

#### **Control Features**

- On/Off control referenced to input return
- Remote sense for the output voltage
- Wide output voltage trim range of +10%, -50%
- Optional: Active current share for parallel applications

#### **Protection Features**

- Input under-voltage lockout
- Output current limit and short circuit protection
- · Active back bias limit
- Auto-recovery output over-voltage protection
- Thermal shutdown

## **Screening/Qualification**

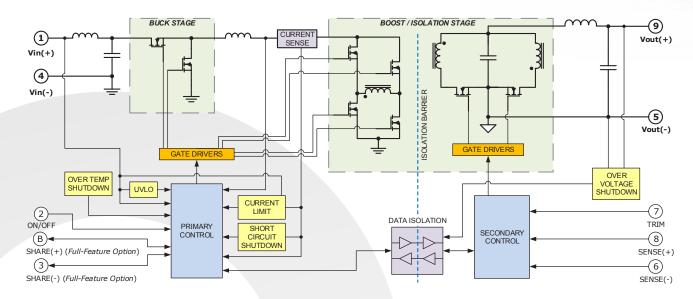
- AS9100 and ISO 9001 certified facility
- Qualified to MIL-STD-810
- Available with S-Grade or M-Grade screening
- Pre-cap inspection per IPC-A-610, Class III
- Temperature cycling per MIL-STD-883, Method 1010, Condition B, 10 cycles
- Burn-In at 100 °C baseplate temperature
- Final visual inspection per MIL-STD-883, Method 2009
- Full component traceability



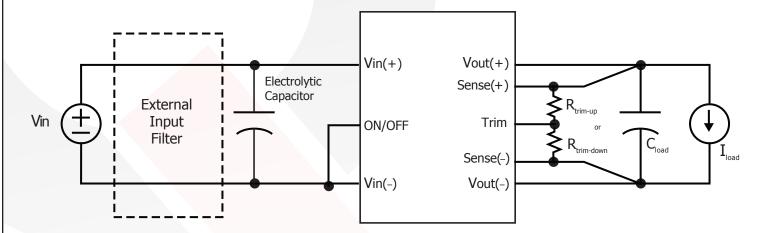
Output: 10.2V

**Current: 49A** 

## **BLOCK DIAGRAM**



#### TYPICAL CONNECTION DIAGRAM



Output: 10.2V Current: 49A

## MCOTS-C-28-10R2-HZ ELECTRICAL CHARACTERISTICS

Ta = 25 °C, Vin = 28dc unless otherwise noted; full operating temperature range is -55 °C to  $\pm 100$  °C baseplate temperature with appropriate power derating. Specifications subject to change without notice.

Parameter	Min.	Тур.	Max.	Units	Notes & Conditions
ABSOLUTE MAXIMUM RATINGS					
Input Voltage					
Non-Operating	-1		75	V	Continuous
Operating			55	V	Continuous
Operating Transient Protection			60	V	100 ms transient, square wave, See Note 6
Isolation Voltage					, , , , , , , , , , , , , , , , , , , ,
Input to Output			2250	Vdc	Basic Insulation, Pollution Degree 2
Input to Baseplate			2250	Vdc	, ,
Output to Baseplate			2250	Vdc	
Operating Temperature	-55		100	°C	Baseplate temperature
Storage Temperature	-65		135	°C	
Voltage at ON/OFF input pin	-2		18	V	
INPUT CHARACTERISTICS				-	
Operating Input Voltage Range	16	28	55	V	60V transient for 100 ms
Input Under-Voltage Lockout					
Turn-On Voltage Threshold	15.1	15.4	15.7	V	
Turn-Off Voltage Threshold	14.2	14.5	14.8	V	
Lockout Voltage Hysteresis	0.5	0.9	1.5	V	
Recommended External Input Capacitance	0.5	470	2.0	μF	Typical ESR 0.1-0.2 Ω
Input Filter Component Values (C <sub>1</sub> \L <sub>1</sub> \C <sub>2</sub> )		47\0.34\23		nF\µH\µF	Internal values; see Figure E
Maximum Input Current		17 (015 1 (25	46	Α	At low line, Full load and 10% trim up
No-Load Input Current		240	400	mA	The form line of all found and 10 % thin ap
Disabled Input Current		3	8	mA	
Response to Input Transient		2		V	0.25 V/us input transient; See Figure 12
Input Terminal Ripple Current		90	180	mA	RMS; See Figure 9
Recommended Input Fuse		30	50	A	Fast acting external fuse recommended
OUTPUT CHARACTERISTICS			50		rust dealing external ruse recommended
Output Voltage Set Point	10.10	10.20	10.31	V	
Output Voltage Regulation	10.120	10.20	10.01		See Note 1
Over Line		±0.35\36	±0.4\41	%\mV	300 11010 1
Over Load		±0.35\36	±0.4\41	%\mV	
Over Temperature	-0.19	±0.08	+0.14	V	Positive temperature coefficient
Total Output Voltage Range	9.94	_5.55	10.50	V	Over sample, line, load, temperature & life
Output Voltage Ripple and Noise	3.3.		10130		20 MHz bandwidth; See Note 2
Peak-to-Peak		135	270	mV	Full Load; 100 µF load cap; See Figure 10
RMS		25	50	mV	Full Load; 100 µF load cap; See Figure 10
Operating Output Current Range	0	23	49	A	Subject to thermal derating
Output DC Current-Limit Inception	53.9	58.0	63.7	A	Output Voltage 10% Low
Output DC Current-Limit Shutdown Voltage	3313	4.1	0317	V	See Note 3
Back-Drive Current Limit while Enabled	13.9	15.5	17.1	A	Negative current drawn from output
Back-Drive Current Limit while Disabled	0	3	8	mA	Negative current drawn from output
Maximum Output Capacitance			10	mF	34 A Resistive Load
Output Voltage during Load Current Transient			10	1111	3 174 Resistive Load
Step Change in Output Current (0.1 A-5 A/µs)		500		mV	50% to 75% to 50% IOUT max, 100 μF load cap
Settling Time		500		μs	To within 1% VOUT nom
Output Voltage Trim Range	-50	300	+10	μs %	Across Pins 8 & 6; Figure C
Output Over-Voltage Protection	12.05	12.50	13.62	V V	Over full temp range
EFFICIENCY	12.03	12.50	13.02	V	Over fail tellip fullye
100% Load		94		%	See Figure 1 for efficiency curve
50% Load		95		%	See Figure 1 for efficiency curve
JU /U LUdu		20		70	Tace rigule 1 for efficiency curve

**Output: 10.2V Current: 49A** 

## MCOTS-C-28-10R2-HZ ELECTRICAL CHARACTERISTICS

Ta = 25 °C, Vin = 28dc unless otherwise noted; full operating temperature range is -55 °C to +100 °C baseplate temperature with appropriate power derating. Specifications subject to change without notice.

DYNAMIC CHARACTERISTICS   Turn-On Transient   Turn-On Transient   Turn-On Time   24   35   40   ms   Full load, Vout=90% nom; See Note 5   Output Voltage Overshoot   5   %   No Load, 10mF load cap	Parameter	Min.	Тур.	Max.	Units	Notes & Conditions
Turn-On Time Output Voltage Overshoot  ISOLATION CHARACTERISTICS  Isolation Voltage (dielectric strength) Isolation Resistance Isolation Capacitance (input to output)  TEMPERATURE LIMITS FOR POWER DERATING CURVES  Semiconductor Junction Temperature  Transformer Temperature  Transformer Temperature, Tb  TEATURE CHARACTERISTICS  Switching Frequency ON/OFF Control Off-State Voltage On-State Voltage ON/OFF Control Pull-Up Noltage Pull-Up Resistance Over-Temperature Shutdown OTP Trip Point Over-Temperature Shutdown Restart Hysteresis  Tusion  Turn-On Time The Maximum Base Full load, Vout=90% nom; See Note 5 No Load, 10mF load cap  Full load, Vout=90% nom; See Note 5 No Load, 10mF load cap  To Maximum Base Full load, Vout=90% nom; See Note 5 No Load, 10mF load cap  To Maximum Base Pote 5 No Load, 10mF load cap  V  V Deach 10m	DYNAMIC CHARACTERISTICS					
Output Voltage Overshoot       ISOLATION CHARACTERISTICS       Isolation Voltage (dielectric strength)     2250     V       Isolation Resistance     30     MΩ       Isolation Capacitance (input to output)     1000     pF     See Note 4       TEMPERATURE LIMITS FOR POWER DERATING CURVES       Semiconductor Junction Temperature     125     °C     Package rated to 150 °C       Board Temperature     125     °C     UL rated max operating temp 130 °C       Transformer Temperature     125     °C     UL rated max operating temp 130 °C       Maximum Baseplate Temperature, Tb     100     °C     FATURE CHARACTERISTICS       Switching Frequency     230     240     250     kHz     Isolation stage switching freq. is half this       ON/OFF Control     00     0     0       ON-State Voltage     2.4     18.0     V       ON/OFF Control     08     V       Pull-Up Voltage     15     18     V       Pull-Up Resistance     50     kΩ       Over-Temperature Shutdown OTP Trip Point     120     °C     Average PCB Temperature       Over-Temperature Shutdown Restart Hysteresis     10     °C	Turn-On Transient					
Isolation Characteristics   Solation Voltage (dielectric strength)   Solation Resistance   30   MΩ   Solation Resistance   1000   pF   See Note 4	Turn-On Time	24	35	40	ms	Full load, Vout=90% nom; See Note 5
Isolation Voltage (dielectric strength)   2250   V     Isolation Resistance   30   MΩ     Isolation Capacitance (input to output)   1000   pF   See Note 4     TEMPERATURE LIMITS FOR POWER DERATING CURVES     Semiconductor Junction Temperature   125   °C     Board Temperature   125   °C     Board Temperature   125   °C     Maximum Baseplate Temperature, Tb   100   °C     FEATURE CHARACTERISTICS     Switching Frequency   230   240   250   kHz   Isolation stage switching freq. is half this     ON/OFF Control   0.8   V     On-State Voltage   2.4   18.0   V     On-State Voltage   2.4   18.0   V     ON/OFF Control   0.8   V     ON/OFF Control   0.8   V     ON/OFF Control   0.8   V     ON/OFF Control   0.8   V     ON/OFF Sistance   15   18   V     Pull-Up Voltage   15   18   V     Pull-Up Resistance   50   kΩ     Over-Temperature Shutdown OTP Trip Point   120   °C     Over-Temperature Shutdown Restart Hysteresis   10   °C     Over-Temperature Shutdown Restart Hysteresis   10   °C     Over-Temperature Shutdown Restart Hysteresis   10   °C     Over-Temperature Shutdown Sistance   10   °C     Over-Temperature Shutdown Sistance   10   °C     Over-Temperature Shutdown Restart Hysteresis   10   °C     Over-Temperature Shutdown Sistance   10   °C     Ov	Output Voltage Overshoot			5	%	No Load, 10mF load cap
Isolation Resistance   30	ISOLATION CHARACTERISTICS					
Isolation Capacitance (input to output)   1000   pF   See Note 4	Isolation Voltage (dielectric strength)		2250		V	
TEMPERATURE LIMITS FOR POWER DERATING CURVESSemiconductor Junction Temperature125°CPackage rated to 150 °CBoard Temperature125°CUL rated max operating temp 130 °CTransformer Temperature125°CUL rated max operating temp 130 °CMaximum Baseplate Temperature, Tb100°CFEATURE CHARACTERISTICSSwitching Frequency230240250kHzIsolation stage switching freq. is half thisON/OFF Control0018.0VVOn-State Voltage2.418.0VON/OFF Control0.8VPull-Up Voltage1518VPull-Up Resistance50kΩOver-Temperature Shutdown OTP Trip Point120°CAverage PCB TemperatureOver-Temperature Shutdown Restart Hysteresis10°CAverage PCB Temperature	Isolation Resistance		30		MΩ	
Semiconductor Junction Temperature125°CPackage rated to 150 °CBoard Temperature125°CUL rated max operating temp 130 °CTransformer Temperature125°CMaximum Baseplate Temperature, Tb100°CFEATURE CHARACTERISTICSSwitching Frequency230240250kHzIsolation stage switching freq. is half thisON/OFF Control2.418.0VOn-State Voltage-2.00.8VON/OFF Control0.8VPull-Up Voltage1518VPull-Up Resistance50kΩOver-Temperature Shutdown OTP Trip Point120°CAverage PCB TemperatureOver-Temperature Shutdown Restart Hysteresis10°C	Isolation Capacitance (input to output)		1000		pF	See Note 4
Board Temperature Transformer Temperature Maximum Baseplate Temperature, Tb  FEATURE CHARACTERISTICS Switching Frequency ON/OFF Control Off-State Voltage ON/OFF Control Pull-Up Voltage Pull-Up Resistance Over-Temperature Shutdown OTP Trip Point Over-Temperature Shutdown Restart Hysteresis  125 °C UL rated max operating temp 130 °C  UL rated max operating temp 130 °C  UL rated max operating temp 130 °C  UL rated max operating temp 130 °C  UL rated max operating temp 130 °C  UL rated max operating temp 130 °C  UL rated max operating temp 130 °C  UL rated max operating temp 130 °C  UL rated max operating temp 130 °C  UL rated max operating temp 130 °C  UL rated max operating temp 130 °C  UL rated max operating temp 130 °C  V  Decrease Switching freq. is half this V  ON/OFF Control Substituting Transformer Shutdown stage switching freq. is half this V  ON/OFF Control Substituting Transformer Shutdown stage switching freq. is half this V  ON/OFF Control Substituting Transformer Shutdown stage switching freq. is half this V  ON/OFF Control Substituting Transformer Shutdown stage switching freq. is half this V  ON/OFF Control Substituting Transformer Shutdown stage switching freq. is half this V  ON/OFF Control Substituting Transformer Shutdown stage switching freq. is half this	TEMPERATURE LIMITS FOR POWER DERATIN	<b>G CURVES</b>				
Transformer Temperature  Maximum Baseplate Temperature, Tb  FEATURE CHARACTERISTICS  Switching Frequency ON/OFF Control Off-State Voltage ON/OFF Control Pull-Up Voltage Pull-Up Resistance Over-Temperature Shutdown OTP Trip Point Over-Temperature Shutdown Restart Hysteresis  125 °C  100 °C  Isolation stage switching freq. is half this  V  Isolation stage switching freq. is half this  V  0.8 V  0.8 V  Average PCB Temperature  °C  Average PCB Temperature	Semiconductor Junction Temperature			125	°C	Package rated to 150 °C
Maximum Baseplate Temperature, Tb       100       °C         FEATURE CHARACTERISTICS         Switching Frequency       230       240       250       kHz       Isolation stage switching freq. is half this         ON/OFF Control       2.4       18.0       V         ON/OFF Control       0.8       V         ON/OFF Control       0.8       V         Pull-Up Voltage       15       18       V         Pull-Up Resistance       50       kΩ         Over-Temperature Shutdown OTP Trip Point       120       °C       Average PCB Temperature         Over-Temperature Shutdown Restart Hysteresis       10       °C	Board Temperature			125	°C	UL rated max operating temp 130 °C
FEATURE CHARACTERISTICS         Switching Frequency       230       240       250       kHz       Isolation stage switching freq. is half this         ON/OFF Control       2.4       18.0       V         On-State Voltage       -2.0       0.8       V         ON/OFF Control       0.8       V         Pull-Up Voltage       15       18       V         Pull-Up Resistance       50       kΩ         Over-Temperature Shutdown OTP Trip Point       120       °C       Average PCB Temperature         Over-Temperature Shutdown Restart Hysteresis       10       °C	Transformer Temperature			125	°C	
Switching Frequency       230       240       250       kHz       Isolation stage switching freq. is half this         ON/OFF Control       2.4       18.0       V         On-State Voltage       -2.0       0.8       V         ON/OFF Control       0.8       V         Pull-Up Voltage       15       18       V         Pull-Up Resistance       50       kΩ         Over-Temperature Shutdown OTP Trip Point       120       °C       Average PCB Temperature         Over-Temperature Shutdown Restart Hysteresis       10       °C       Average PCB Temperature	Maximum Baseplate Temperature, Tb			100	°C	
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	FEATURE CHARACTERISTICS					
Off-State Voltage       2.4       18.0       V         On-State Voltage       -2.0       0.8       V         ON/OFF Control       V       V         Pull-Up Voltage       15       18       V         Pull-Up Resistance       50       kΩ         Over-Temperature Shutdown OTP Trip Point       120       °C       Average PCB Temperature         Over-Temperature Shutdown Restart Hysteresis       10       °C	Switching Frequency	230	240	250	kHz	Isolation stage switching freq. is half this
On-State Voltage       -2.0       0.8       V         ON/OFF Control       0.8       V         Pull-Up Voltage       15       18       V         Pull-Up Resistance       50       kΩ         Over-Temperature Shutdown OTP Trip Point       120       °C       Average PCB Temperature         Over-Temperature Shutdown Restart Hysteresis       10       °C	ON/OFF Control					
$\begin{array}{c ccccccccccccccccccccccccccccccccccc$	Off-State Voltage	2.4		18.0	V	
Pull-Up Voltage     15     18     V       Pull-Up Resistance     50 $kΩ$ Over-Temperature Shutdown OTP Trip Point     120     °C     Average PCB Temperature       Over-Temperature Shutdown Restart Hysteresis     10     °C	On-State Voltage	-2.0		0.8	V	
Pull-Up Resistance $S_{0}$ $S$	ON/OFF Control					
Over-Temperature Shutdown OTP Trip Point 120 °C Average PCB Temperature Over-Temperature Shutdown Restart Hysteresis 10 °C	Pull-Up Voltage		15	18	V	
Over-Temperature Shutdown Restart Hysteresis 10 °C	Pull-Up Resistance		50		kΩ	
	Over-Temperature Shutdown OTP Trip Point		120		°C	Average PCB Temperature
RELIABILITY CHARACTERISTICS	Over-Temperature Shutdown Restart Hysteresis		10		°C	
	RELIABILITY CHARACTERISTICS					
Calculated MTBF per MIL-HDBK-217F (GB) 4.1   106 Hrs.   Tb = 70 °C	Calculated MTBF per MIL-HDBK-217F (GB)		4.1		106 Hrs.	Tb = 70 °C
Calculated MTBF per MIL-HDBK-217F (GM) 0.92 10 <sup>6</sup> Hrs. Tb = 70 °C	. ,		0.92		106 Hrs.	Tb = 70 °C

Note 1: Line and load regulation is limited by duty cycle quantization and does not indicate a shift in the internal voltage reference.

Note 2: For applications requiring reduced output voltage ripple and noise, consult SynQor applications support (e-mail: support@synqor.com).

Note 3: If the output voltage falls below the Output DC Current Limit Shutdown Voltage for more than 50ms, then the unit will enter into hiccup mode, with a

Note 4: Higher values of isolation capacitance can be added external to the module.

Note 5: Add 25ms to Full-Featured Turn-On Enable time to allow synchronization.

Note 6: Loss of regulation possible if input voltage transient exceeds 60V.

## STANDARDS COMPLIANCE

**Parameter Notes & Conditions** 

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STANDARDS COMPLIANCE	Pending	
UL 62368-1	Basic Insulation	
CAN/CSA C22.2 No.62368-1		
FN 62368		

Note: An external input fuse must always be used to meet these safety requirements. Contact SynQor for official safety certificates on new releases or



Output: 10.2V // Current: 49A

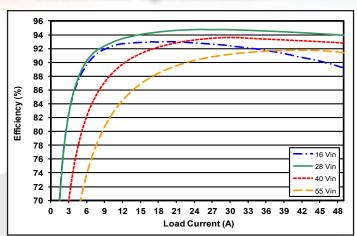


Figure 1: Efficiency at nominal output voltage vs. load current for minimum, nominal, and maximum input voltages at 25 °C.

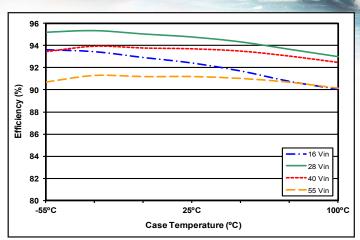


Figure 2: Efficiency at nominal output voltage and 60% rated power vs. case temperature for minimum, nominal, and maximum input voltages.

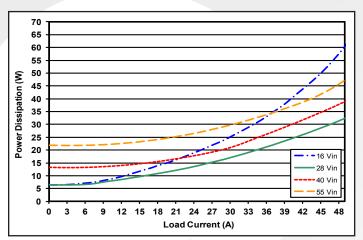


Figure 3: Power Dissipation at nominal output voltage vs. load current for minimum, nominal, and maximum input voltages at 25 °C.

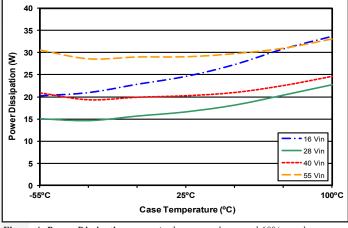


Figure 4: Power Dissipation at nominal output voltage and 60% rated power vs. case temperature for minimum, nominal, and maximum input voltages.

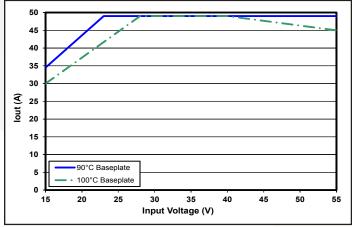


Figure 5: Thermal Derating (maximum output current vs. continuous input voltage) at selected baseplate temperatures.

Note: Transients lasting ≤100 ms need no further derating.

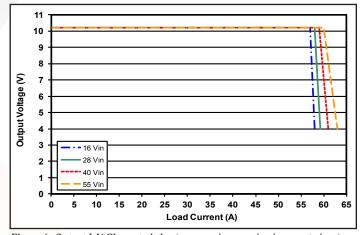


Figure 6: Output I-V Characteristics (output voltage vs. load current) showing typical current limit curves. See Current Limit section in the Application Notes.



Output: 10.2V / Current: 49A

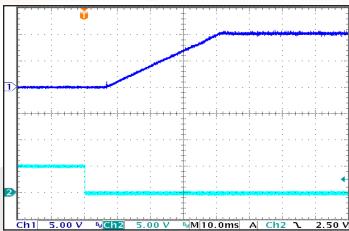


Figure 7: Typical startup waveform. Input voltage pre-applied, ON/OFF Pin on Ch 2. Ch 1: Vout (5V/div); Ch 2: ON/OFF Pin (5V/div). Timescale: 10.0ms/div.

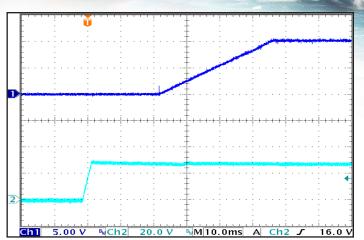


Figure 8: Turn-on transient at full resistive load and zero output capacitance initiated by Vin. Ch 1: Vin (5V/div). Ch 2: Vout (20V/div). Timescale: 10.0ms/div.

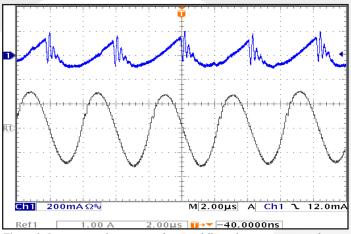


Figure 9: Input terminal current ripple, i<sub>C</sub> at full rated output current with 470µF electrolytic capacitance. Ch 1: 28 Vin (200mA/div), Ref1: 50 Vin (1A/div). Bandwidth: 20MHz. Timescale: 2.00µs/div. See Figure 13.

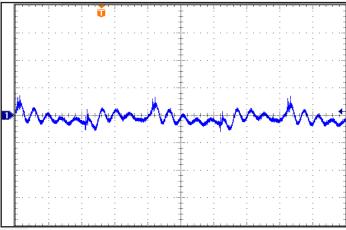


Figure 10: Output voltage ripple, Vout, at nominal input voltage and rated load current (100 mV/div). Load capacitance: 1µF ceramic capacitor and 100µF electrolytic capacitor. Bandwidth: 20 MHz. Timescale: 2.00µs/div. See Figure 13.

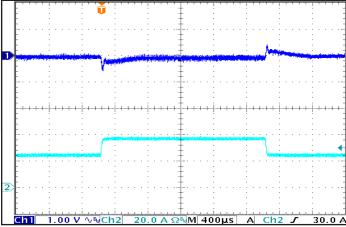


Figure 11: Output voltage response to step-change in load current (50%-75%-50% of Iout(max);  $dI/dt = 5 A/\mu s$ ). Load cap:  $I\mu F$  ceramic and  $I00\mu F$  electrolytic capacitors. Ch 1: Vout (IV/div), Ch 2: Iout (IV/div). Timescale:

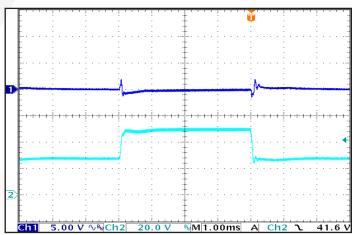


Figure 12: Output voltage response to step-change in input voltage (250V/ms). Load cap: 100µF electrolytic output capacitance. Ch 1: Vout (5V/div), Ch 2: Vin (20V/div). Timescale: 1.00ms/div.

Output: 10.2V

Current: 49A

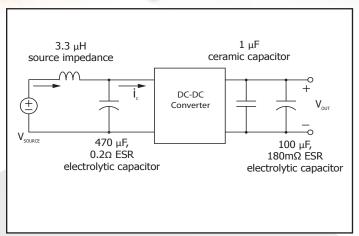


Figure 13: Test Set-up Diagram showing measurement points for Input Terminal Current Ripple (Figure 9) and Output Voltage Ripple (Figure 10).

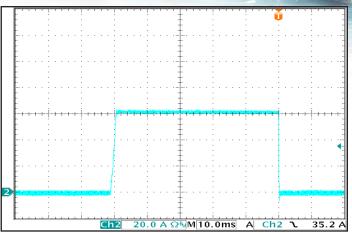


Figure 14: Output Short Load Current (20 A/div) as a function of time (20 ms/div) when the converter attempts to turn on into a 1 m $\Omega$  short circuit.

**Output: 10.2V** 

Current: 49A

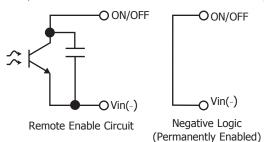
#### **BASIC OPERATION AND FEATURES**

This converter series uses a two-stage power conversion topology. The first stage keeps the output voltage constant over variations in line, load, and temperature. The second stage uses a transformer to provide the functions of input/output isolation and voltage stepdown to achieve the low output voltage required.

Both the first stage and the second stage switch at a fixed frequency for predictable EMI performance. Rectification of the transformer's output is accomplished with synchronous rectifiers. These devices, which are MOSFETs with a very low on-state resistance, dissipate significantly less energy than Schottky diodes, enabling the converter to achieve high efficiency.

Dissipation throughout the converter is so low that it does not require a heatsink for operation in many applications; however, adding a heatsink provides improved thermal derating performance in extreme situations. To further withstand harsh environments and thermally demanding applications, the converter is available totally encased. See Ordering Information page for available thermal design options.

SynQor half-brick converters use the industry standard footprint and pin-out.



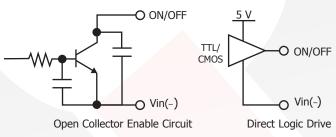


Figure A: Various Circuits for Driving the ON/OFF Pin

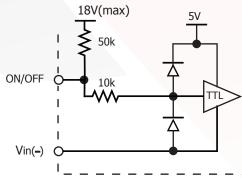


Figure B: Internal ON/OFF Pin Circuitry

#### **CONTROL FEATURES**

REMOTE ON/OFF (Pin 2): The ON/OFF input, Pin 2, permits the user to control when the converter is on or off. This input is referenced to the return terminal of the input bus, Vin(-).

In the negative logic version, the ON/OFF signal is active low (meaning that a low voltage turns the converter on). Figure A details possible circuits for driving the ON/OFF pin. Figure B is a detailed look of the internal ON/OFF circuitry.

**REMOTE SENSE Pins 8(+) and 6(-):** The SENSE(+) and SENSE(-) inputs correct for voltage drops along the conductors that connect the converter's output pins to the load.

Pin 8 should be connected to Vout(+) and Pin 6 should be connected to Vout(-) at the point on the board where regulation is desired. If these connections are not made, the converter will deliver an output voltage that is slightly higher than its specified

Note: The Output Over-Voltage Protection circuit senses the voltage across the output (Pins 9 and 5) to determine when it should trigger, not the voltage across the converter's sense leads (Pins 8 and 6). Therefore, the resistive drop on the board should be small enough so that output OVP does not trigger, even during load transients.

**OUTPUT VOLTAGE TRIM (Pin 7):** The TRIM input permits the user to adjust the output voltage across the sense leads up or down according to the trim range specifications. SynQor uses industry standard trim equations.

To decrease the output voltage, the user should connect a resistor between Pin 7 (TRIM) and Pin 6 (SENSE(-) input). For a desired decrease of the nominal output voltage, the value of the resistor should be:

$$Rtrim-down = \left(\frac{100\%}{\Delta\%} - 2\right) k\Omega$$

where

$$\Delta\% = \left| \frac{\text{Vnominal} - \text{Vdesired}}{\text{Vnominal}} \right| \times 100\%$$

To increase the output voltage, the user should connect a resistor between Pin 7 (TRIM) and Pin 8 (SENSE(+) input). For a desired increase of the nominal output voltage, the value of the resistor should be:

$$Rtrim-up = \underbrace{ \left( \frac{Vnominal}{1.225} - 2 \right) \times Vdesired + Vnominal}_{Vdesired - Vnominal} k\Omega$$

The Trim Graph in Figure C shows the relationship between the trim resistor value and Rtrim-up and Rtrim-down, showing the total range the output voltage can be trimmed up or down.

**Note:** The TRIM feature does not affect the voltage at which the output over-voltage protection circuit is triggered. Trimming the output voltage too high may cause the over-voltage protection circuit to engage, particularly during transients.

It is not necessary for the user to add capacitance at the TRIM pin. The node is internally filtered to eliminate noise.

**Total DC Variation of Vout:** For the converter to meet its full specifications, the maximum variation of the DC value of Vout, due to both trimming and remote load voltage drops, should not be greater than that specified for the output voltage trim range.

**Active Trimming:** Active trimming of the output voltage is supported, but dynamic active trimming with feedback is discouraged due to the potential for limit-cycling. If such trimming is necessary, control loop bandwidth should be limited to <1 Hz. A deadband which is at least as large as the line/load regulation specification is also recommended, but not required.

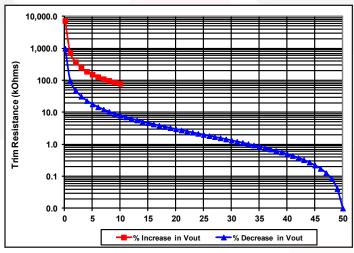


Figure C: Trim Graph

#### **Protection Features**

**Input Under-Voltage Lockout (UVLO):** The converter is designed to turn off when the input voltage is too low, helping to avoid an input system instability problem, which is described in more detail in the application note titled "Input System Instability" on the SynQor website. The lockout circuitry is a comparator with DC hysteresis. When the input voltage is rising, it must exceed the typical "Turn-On Voltage Threshold" value\* before the converter will turn on. Once the converter is on, the input voltage must fall below the typical Turn-Off Voltage Threshold value before the converter will turn off.

**Output Current Limit (OCP):** If the output current exceeds the "Output DC Current Limit Inception" value\*, then a fast linear current limit controller will reduce the output voltage to maintain a constant output current. If as a result, the output voltage falls below the "Output DC Current Limit Shutdown Voltage"\* for more than 50 ms\*\*, then the unit will enter into hiccup mode, with a 500 ms off-time. The unit will then automatically attempt to restart.

**Back-Drive Current Limit:** If there is negative output current of a magnitude larger than the "Back-Drive Current Limit while Enabled" specification\*, then a fast back-drive limit controller will increase the output voltage to maintain a constant output current. If this results in the output voltage exceeding the "Output Over-Voltage Protection" threshold\*, then the unit will shut down.

**Output Over-Voltage Limit (OVP):** If the voltage across the output pins exceeds the Output Over-Voltage Protection threshold, the converter will immediately stop switching. This prevents damage to the load circuit due to 1) excessive series resistance in output current path from converter output pins to sense point, 2) a release of a short-circuit condition, or 3) a release of a current limit condition. Load capacitance determines exactly how high the output voltage will rise in response to these conditions. After 500 ms the converter will automatically restart.

**Over-Temperature Shutdown (OTP):** A temperature sensor on the converter senses the average temperature of the module. The thermal shutdown circuit is designed to turn the converter off when the temperature at the sensed location reaches the "Over-Temperature Shutdown" value\*. It will allow the converter to turn on again when the temperature of the sensed location falls by the amount of the "Over-Temperature Shutdown Restart Hysteresis" value\*.

**Startup Inhibit Period:** The Startup Inhibit Period ensures that the converter will remain off for approximately 500 ms when it is shut down due to a fault. This generates a 2 Hz "hiccup mode," which prevents the converter from overheating. There are multiple ways that the converter can be shut down, initiating a Startup Inhibit Period:

- Output Over-Voltage Protection
- Current Limit
- Short Circuit Protection
- \* See Electrical Characteristics section.
- \*\* Certain models may have an extended on-time, longer than 50 ms. See Electrical Characteristics section.

Output: 10.2V Current: 49A

#### **APPLICATION CONSIDERATIONS**

**Input System Instability:** This condition can occur because any DC-DC converter appears incrementally as a negative resistance load. A detailed application note titled "Input System Instability" is available on the SynQor website which provides an understanding of why this instability arises, and shows the preferred solution for correcting it.

**Application Circuits:** A typical circuit diagram, Figure D below details the input filtering and voltage trimming.

**Input Filtering and External Input Capacitance:** Figure E below shows the internal input filter components. This filter dramatically reduces input terminal ripple current, which otherwise could exceed the rating of an external electrolytic input capacitor. The recommended external input capacitance is specified in the Input Characteristics section of the Electrical Specifications. More detailed information is available in the application note titled "EMI Characteristics" on the SynQor website.

**Output Filtering and External Output Capacitance:** The internal output filter components are shown in Figure E below. This filter dramatically reduces output voltage ripple. Some minimum external output capacitance is required, as specified in the Output Characteristics area of the Electrical Characteristics section. No damage will occur without this capacitor connected, but peak output voltage ripple will be much higher.

**Thermal Considerations:** For baseplated and encased versions, the max operating baseplate temperature, TB, is 100 °C. Refer to the Thermal Derating Curves in the Technical Figures section to see the available output current at baseplate temperatures below 100 °C.

A power derating curve can be calculated for any heatsink that is attached to the base-plate of the converter. It is only necessary to determine the thermal resistance, RTHBA, of the chosen heatsink between the baseplate and the ambient air for a given airflow rate. This information is usually available from the heatsink vendor. The following formula can the be used to determine the maximum power the converter can dissipate for a given thermal condition if its base-plate is to be no higher than 100 °C.

$$P_{\text{diss}}^{\text{max}} = \frac{100 \text{ °C - TA}}{\text{RTHBA}}$$

This value of maximum power dissipation can then be used in conjunction with the data shown in the Power Dissipation Curves in the Technical Figures section to determine the maximum load current (and power) that the converter can deliver in the given thermal condition.

For convenience, Thermal Derating Curves are provided in the Technical Figures section.

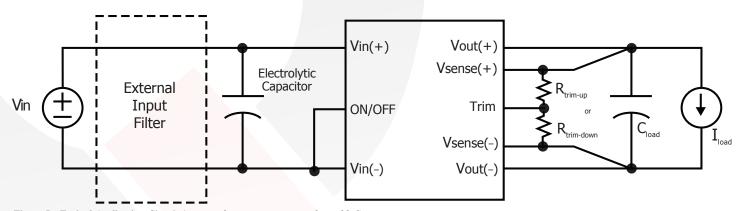


Figure D: Typical Application Circuit (negative logic unit, permanently enabled)

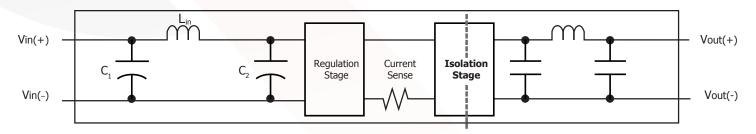


Figure E: Internal Input and Output Filter Diagram (component values listed in Electrical Characteristics section)

Output: 10.2V Current: 49A

# **Active Current Share Application Section**

**Overview:** The full-featured option, which is specified by an "F" as the last character of the part number, supports current sharing by adding two additional pins: SHARE(+) and SHARE(-)

**Connection of Paralleled Units:** Up to 100 units can be placed in parallel. In this current share architecture, one unit is dynamically chosen to act as a master, controlling all other units. It cannot be predicted which unit will become the master at any given time, so units should be wired symmetrically (see Figures F & G).

- Input power pins and output power pins should be tied together between units, preferably with wide overlapping copper planes, after any input common-mode choke.
- The SHARE(+) and SHARE(-) pins should be routed between all paralleled units as a differential pair.
- The ON/OFF pins should be connected in parallel, and rise/fall times should be kept below 2 ms.
- The SENSE(+) and SENSE(-) pins should be connected either locally at each unit or separately to a common sense point. If an output common-mode choke is used, sense lines should be connected on the module-side of the choke.
- If the TRIM pin is used, then each unit should have its own trim resistor connected locally between TRIM and SENSE(+) or SENSE(-).

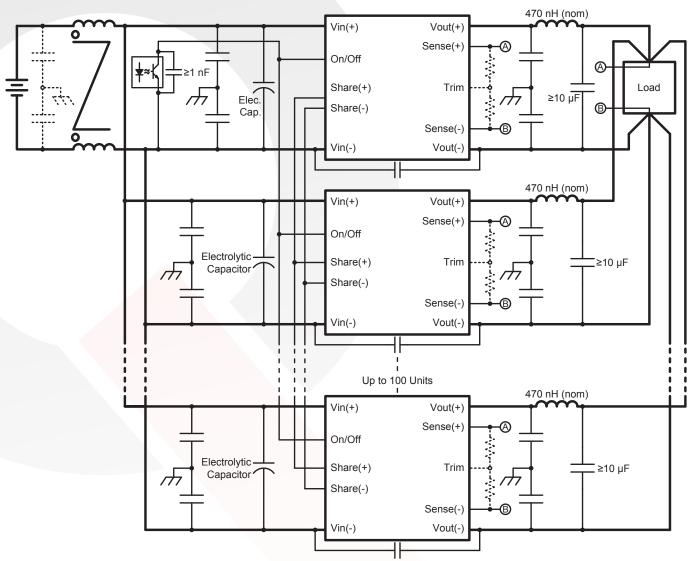


Figure F: Typical Application Circuit for Paralleling of Full-Featured Units with an Input Common-Mode Choke. If an input common-mode choke is used, Vin(-) MUST be tied together AFTER the choke for all units. 470 nH (nominal) inductor or an output common-mode choke is required for outputs >18 V. See Figure G for output common-mode choke configuration.

**Automatic Configuration:** The micro-controller inside each power converter unit is programmed at the factory with a unique chip number. In every other respect, each shared unit is identical and has the same orderable part number.

On initial startup (or after the master is disabled or shuts down), each unit determines the chip number of every other unit currently connected to the shared serial bus formed by the SHARE(+) and SHARE(-) pins. The unit with the highest chip number dynamically reconfigures itself from slave to master. The rest of the units (that do not have the highest chip number) become slaves.

The master unit then broadcasts its control state over the shared serial bus on a cycle-by-cycle basis. The slave units interpret and implement the control commands sent by the master, mirroring every action of the master unit.

If the master is disabled or encounters a fault condition, all units will immediately shut down, and if the master unit is unable to restart, then the unit with the next highest chip number will become master. If a slave unit is disabled or encounters a fault condition, all other units continue to run, and the slave unit can restart seamlessly.

**Automatic Interleaving:** The slave units automatically lock frequency with the master, and interleave the phase of their switching transitions for improved EMI performance. To obtain the phase angle relative to the master, each slave divides 360 degrees by the total number of connected units, and multiples the result by its rank among chip numbers of connected units.

**ORing Diodes** placed in series with the converter outputs must also have a resistor smaller than 500  $\Omega$  placed in parallel. This resistor keeps the output voltage of a temporarily disabled slave unit consistent with the active master unit. If the output voltage of the slave unit were allowed to totally discharge, and the slave unit tried to restart, it would fail because the slave reproduces the duty cycle of the master unit, which is running in steady state and cannot repeat an output voltage soft-start.

**Common-Mode Filtering** must be either a single primary side choke handling the inputs from all the paralleled units, or multiple chokes placed on the secondary side. This ensures that a solid Vin(-) plane is maintained between units. Adding a common-mode choke at the output eliminates the need for the 470 nH indcutor at the output of shared units when Vout > 18 V. If an output common-mode choke is used, sense connections must be made on the module-side of the choke.

Resonance Between Output Capacitors is Possible: When multiple higher-voltage modules are paralleled, it is possible to excite a series resonance between the output capacitors internal to the module and the parasitic inductance of the module output pins. This is especially likely at higher output voltages where the module internal capacitance is relatively small. This problem is independent of external output capacitance. For modules with an output voltage greater than 18 V, to ensure that this resonant frequency is below the switching frequency it is recommended to add a nominal 470 nH of inductance, located close to the module, in series with each converter output. There must be at least 10 µF of capacitance per converter, located on the load-side of that inductor. The inductance could be from the leakage inductance of a secondary-side common-mode choke; in which case the output capacitor should be appropriately sized for the chosen choke. When using an output common-mode choke, the Sense lines must be connected on the module-side of the common-mode choke (see Figure G).

**RS-485 Physical Layer:** The internal RS-485 transceiver includes many advanced protection features for enhanced reliability:

- Current Limiting and Thermal Shutdown for Driver Overload Protection
- IEC61000 ESD Protection to +/- 16.5 kV
- Hot Plug Circuitry SHARE(+) and SHARE(-)
   Outputs Remain Tri-State During Power-up/Power-down

**Internal Schottky Diode Termination:** Despite signaling at high speed with fast edges, external termination resistors are not necessary. Each receiver has four Schottky diodes built in, two for each line in the differential pair. These diodes clamp any ringing caused by transmission line reflections, preventing the voltage from going above about 5.5 V or below about -0.5 V. Any subsequent ringing then inherently takes place between 4.5 and 5.5 V or between -0.5 and 0.5 V. Since each receiver on the bus contains a set of clamping diodes to clamp any possible transmission line reflection, the bus does not necessarily need to be routed as a daisy-chain.

Pins SHARE(+) and SHARE(-) are referenced to Vin(-), and therefore should be routed as a differential pair near the Vin(-) plane for optimal signal integrity. The maximum difference in voltage between Vin(-) pins of all units on the share-bus should be kept within 0.3 V to prevent steady-state conduction of the termination diodes. Therefore, the Vin(-) connections to each unit must be common, preferably connected by a single copper plane.

**Share Accuracy:** Inside each converter micro-controller, the duty cycle is generated digitally, making for excellent duty cycle matching between connected units. Some small duty cycle mismatch is caused by (well controlled) process variations in the MOSFET gate drivers. However, the voltage difference induced by this duty cycle mismatch appears across the impedance of the entire power converter, from input to output, multiplied by two, since the differential current flows out of one converter and into another. So, a small duty cycle mismatch yields very small differential currents, which remain small even when 100 units are placed in parallel.

In other current-sharing schemes, it is common to have a current-sharing control loop in each unit. However, due to the limited bandwidth of this loop, units do not necessarily share current on startup or during transients before this loop has a chance to respond. In contrast, the current-sharing scheme used in this product has no control dynamics: control signals are transmitted fast enough that the slave units can mirror the control state of the master unit on a cycle-by-cycle basis, and the current simply shares properly, from the first switching cycle to the last.

Output: 10.2V

**Current: 49A** 

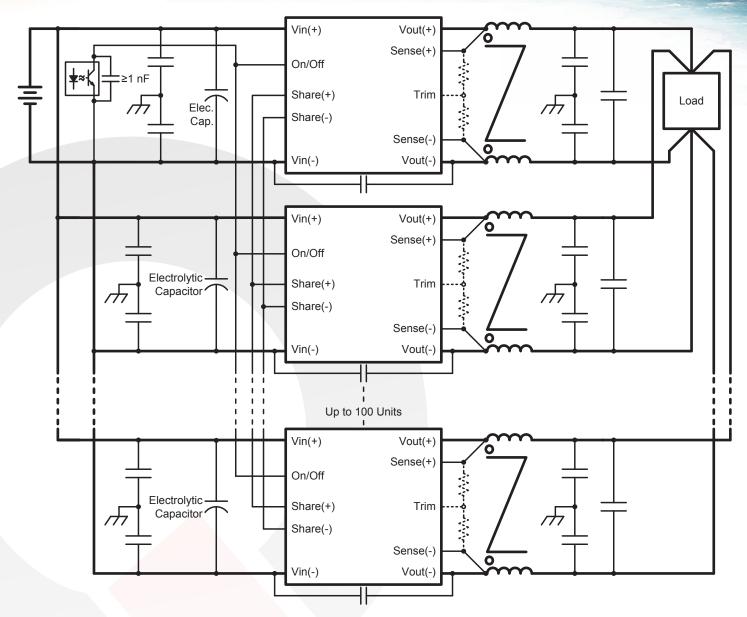
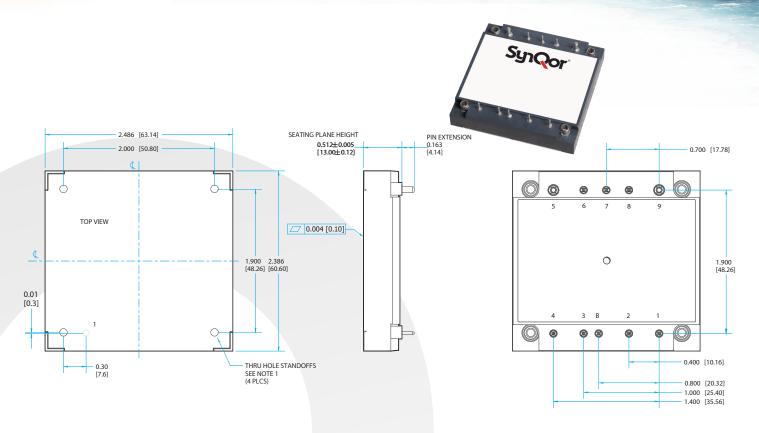


Figure G: Typical Application Circuit for Paralleling of Full-Featured Units with an Output Common-Mode Choke. When using an output common-mode choke, SENSE lines must be connected on the module-side of the choke. See Figure F for configuration with an input common-mode choke.



Output: 10.2V

**Current: 49A** 



#### **NOTES**

- 1) THREADED: APPLIED TORQUE PER M3 SCREW NOT TO EXCEED 6 in-lb (0.7 Nm).
  - NONTHREADED: DIA 0.125" (3.18 mm)
- 2) BASEPLATE FLATNESS TOLERANCE IS 0.004" (0.10 mm) TIR FOR SURFACE.
- 3) PINS 1-4, B AND 6-8 ARE 0.040" (1.02 mm) DIA. WITH 0.080" (2.03 mm) DIA. STANDOFFS.
- 4) PINS 5 AND 9 ARE 0.080" (2.03 mm) DIA. WITH 0.125" (3.18 mm) **DIA STANDOFFS**
- 5) ALL PINS: MATERIAL: COPPER ALLOY FINISH: MATTE TIN OVER NICKEL PLATE
- 6) WEIGHT: 5.2 oz. (146 g)
- 7) ALL DIMENSIONS IN INCHES (mm) TOLERANCES: X.XX IN +/-0.02 (X.X mm +/-0.5 mm) X.XXX IN +/-0.010 (X.XX mm +/-0.25 mm)

#### **PIN DESIGNATIONS**

			Function
L	Vin(+)	+VIN	Positive input voltage
2	ON/OFF	ON/OFF	TTL input to turn converter on and off, referenced to Vin(–), with internal pull up.
3	SHARE(+)	SHARE+	Active current share differential pair (see
3	SHARE(-)	SHARE-	Full-Feature Application Notes)4
1	Vin(-)	IN RTN	Input Return
5	Vout(-)	OUT RTN	Ouput Return
5	SENSE(-)	-SNS	Negative remote sense <sup>1</sup>
7	TRIM	TRIM	Output voltage trim <sup>2</sup>
3	SENSE(+)	+SNS	Positive remote sense <sup>3</sup>
)	Vout(+)	+VOUT	Positive output voltage
1	3	SHARE(+) SHARE(-) Vin(-) SENSE(-) TRIM SENSE(+)	ON/OFF ON/OFF  SHARE(+) SHARE+ SHARE(-) SHARE- Vin(-) IN RTN Vout(-) OUT RTN SENSE(-) -SNS TRIM TRIM SENSE(+) +SNS

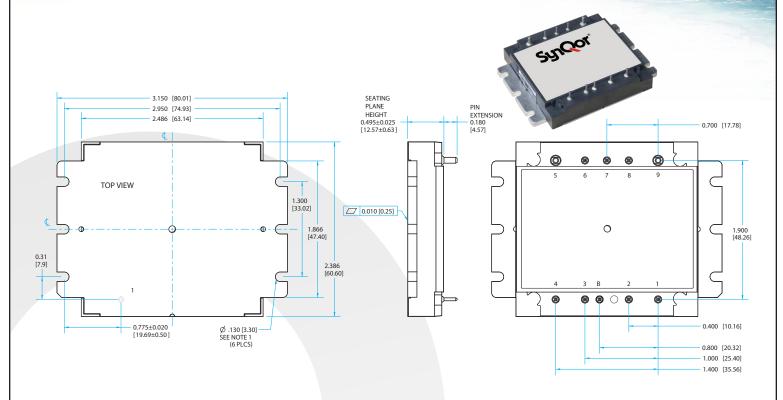
#### Notes:

- 1) SENSE(-) should be connected to Vout(-) either remotely or at the converter.
- Leave TRIM pin open for nominal output voltage.
- 3) SENSE(+) should be connected to Vout(+) either remotely or at the converter.
- On standard product, Pin B & Pin 3 are absent



Output: 10.2V

**Current: 49A** 



#### **NOTES**

- 1) APPLIED TORQUE PER M3 OR 4-40 SCREW NOT TO EXCEED 6 in-lb (0.7 Nm)
- 2) BASEPLATE FLATNESS TOLERANCE IS 0.010" (.25 mm) TIR FOR SURFACE.
- 3) PINS 1-4, 6-8 AND B ARE 0.040" (1.02 mm) DIA. WITH 0.080" (2.03 mm) DIA. STANDOFFS.
- PINS 5 AND 9 ARE 0.080" (2.03 mm) DIA. WITH 0.125" (3.18 mm) DIA STANDOFFS
- 5) ALL PINS: MATERIAL: COPPER ALLOY FINISH: MATTE TIN OVER NICKEL PLATE
- 6) WEIGHT: 5.4 oz. (152 g)
- 7) ALL DIMENSIONS IN INCHES (mm)
  TOLERANCES: X.XX IN +/-0.02 (X.X mm +/-0.5 mm)
  X.XXX IN +/-0.010 (X.XX mm +/-0.25 mm)

#### **PIN DESIGNATIONS**

Pin	Name	Label	Function		
1	Vin(+)	+VIN	Positive input voltage		
2	ON/OFF	ON/OFF	TTL input to turn converter on and off, referenced to Vin(–), with internal pull up.		
В	SHARE(+)	SHARE+	Active current share differential pair (se		
3	SHARE(-)	SHARE-	Full-Feature Application Notes)4		
4	Vin(-)	IN RTN	Input Return		
5	Vout(-)	OUT RTN	Ouput Return		
6	SENSE(-)	-SNS	Negative remote sense <sup>1</sup>		
7	TRIM	TRIM	Output voltage trim <sup>2</sup>		
8	SENSE(+)	+SNS	Positive remote sense <sup>3</sup>		
9	Vout(+)	+VOUT	Positive output voltage		

#### Notes:

- SENSE(-) should be connected to Vout(-) either remotely or at the converter.
- 2) Leave TRIM pin open for nominal output voltage.
- SENSE(+) should be connected to Vout(+) either remotely or at the converter.
- 4) On standard product, Pin B & Pin 3 are absent

Output: 10.2V / Current: 49A

## **Mil-COTS Qualification**

Test Name	<b>Details</b>	# Tested (# Failed)	Consistent with MIL-STD-883F Method
Life Testing	Visual, mechanical and electrical testing before, during and after 1000 hour burn-in @ full load	15 (0)	Method 1005.8
Shock-Vibration Visual, mechanical and electrical testing before, during and after shock and vibration tests		5 (0)	MIL-STD-202, Methods 201A & 213B
+85 °C, 95% RH, 1000 hours, 2 minutes on / 6 hours off		8 (0)	Method 1004.7
Temperature Cycling	500 cycles of -55 °C to +100 °C (30 minute dwell at each temperature)	10 (0)	Method 1010.8, Condition A
Solderability	15 pins	15 (0)	Method 2003
<b>DMT</b>	-65 °C to +110 °C across full line and load specifications in 5 °C steps	7 (0)	
Altitude	70,000 feet (21 km), see Note	2 (0)	

Note: A conductive cooling design is generally needed for high altitude applications because of naturally poor convective cooling at rare atmospheres.

#### **Mil-COTS Converter and Filter Screening**

Screening	Process Description	S-Grade	M-Grade
<b>Baseplate Operating Temperature</b>		-55 °C to +100 °C	-55 °C to +100 °C
Storage Temperature		-65 °C to +135 °C	-65 °C to +135 °C
Pre-Cap Inspection	IPC-A-610, Class III	•	•
Temperature Cycling	MIL-STD-883F, Method 1010, Condition B, 10 Cycles		•
Burn-In	100 °C Baseplate	12 Hours	96 Hours
Final Electrical Test	100%	25 °C	-55 °C, +25 °C, +100 °C
Final Visual Inspection	MIL-STD-883F, Method 2009	•	•

## Mil-COTS MIL-STD-810G Qualification Testing

MIL-STD-810G Test	Method	Description
Fungus	508.6	Table 508.6-I
Altitude	500.5 - Procedure I	Storage: 70,000 ft / 2 hr duration
Aititude	500.5 - Procedure II	Operating: 70,000 ft / 2 hr duration; Ambient Temperature
<b>Rapid Decompression</b>	500.5 - Procedure III	Storage: 8,000 ft to 40,000 ft
Acceleration	513.6 - Procedure II	Operating: 15 g
Salt Fog	509.5	Storage
High Temperature	501.5 - Procedure I	Storage: 135 °C / 3 hrs
nigii reiliperature	501.5 - Procedure II	Operating: 100 °C / 3 hrs
Low Temperature	502.5 - Procedure I	Storage: -65 °C / 4 hrs
Low remperature	502.5 - Procedure II	Operating: -55 °C / 3 hrs
<b>Temperature Shock</b> 503.5 - Procedure I - C		Storage: -65 °C to 135 °C; 12 cycles
Rain	506.5 - Procedure I	Wind Blown Rain
Immersion	512.5 - Procedure I	Non-Operating Non-Operating
Humidity	507.5 - Procedure II	Aggravated cycle @ 95% RH (Figure 507.5-7 aggravated temp - humidity cycle, 15 cycles)
Random Vibration	514.6 - Procedure I	10 - 2000 Hz, PSD level of 1.5 $g^2/Hz$ (54.6 $g_{rms}$ ), duration = 1 hr/axis
Shock	516.6 - Procedure I	20 g peak, 11 ms, Functional Shock (Operating no load) (saw tooth)
SHOCK	516.6 - Procedure VI	Bench Handling Shock
Sinusoidal vibration 514.6 - Category 14 Ro		Rotary wing aircraft - helicopter, 4 hrs/axis, 20 g (sine sweep from 10 - 500 Hz)
Sand and Dust	510.5 - Procedure I	Blowing Dust
Juliu allu Dust	510.5 - Procedure II	Blowing Sand

Output: 10.2V Current: 49A

## **Ordering Information/ Part Numbering**

#### Example MCOTS-C-28-10R2-HZ-N-M-F

Not all combinations make valid part numbers, please contact SynQor for availability. See product summary page for details.

Famil	Product	Input Voltage	Output Voltage	Package	Heatsink Option	Screening Level	Options
MCOTS	C: Converter	<b>28:</b> 16-55V	<b>10R2:</b> 10.2V	<b>HZ:</b> Half Brick Zeta	N: Normal Threaded D: Normal Non-Threaded F: Flanged	<b>S:</b> S-Grade <b>M:</b> M-Grade	[ ]: Standard Feature F: Full Feature

## **APPLICATION NOTES**

A variety of application notes and technical white papers can be downloaded in pdf format from our website.

### Contact SynQor for further information and to order:

**Phone:** 978-849-0600 **Toll Free:** 888-567-9596 **Fax:** 978-849-0602

**E-mail**: power@synqor.com **Web**: www.synqor.com **Address**: 155 Swanson Road

Boxborough, MA 01719

USA

## **PATENTS**

SynQor holds numerous U.S. patents, one or more of which apply to most of its power conversion products. Any that apply to the product(s) listed in this document are identified by markings on the product(s) or on internal components of the product(s) in accordance with U.S. patent laws. SynQor's patents include the following:

6,896,526 6,927,987 7,050,309 7,765,687

7,787,261 8,149,597 8,644,027

#### WARRANTY

SynQor offers a two (2) year limited warranty. Complete warranty information is listed on our website or is available upon request from SynQor.